



**Microsemi Corp.**  
The diode experts

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**JAN1N4148-1**

**FEATURES**

- MICROMINIATURE PACKAGE
- TRIPLE LAYER PASSIVATION
- HERMETICALLY SEALED GLASS PACKAGE
- JANTX AND TXV TYPES AVAILABLE PER MIL-S-19500/116

**MAXIMUM RATINGS**

Operating Temperature: -65°C to +200°C  
 Storage Temperature: -65°C to +200°C  
 Forward Surge Current: 2.0A (8.3 msec.)  
 Thermal Impedance: 50°C/W @ 10 ms  
 Thermal Resistance: 250°C/W @ 0.375"

**ELECTRICAL CHARACTERISTICS** at 25°C unless otherwise specified.

$V_{BR}$	$V_{RWM}$	$I_0$	$V_f$ @ $I_f = 100\text{ mA}$	$V_f$ @ $I_f = 10\text{ mA}$	$t_{rr}$ (Note 1)	$V_{fr}$ (Note 2)
Volts (pk)	Volts (pk)	mA	V dc	V dc	nsec	nsec
100	75	200	1.2	1.0	5	20

$I_R$ @ 20V dc	$I_R$ @ 75V dc	$I_R$ @ 20V $T_A = 150^\circ\text{C}$	$I_R$ @ 75V dc $T_A = 150^\circ\text{C}$	CAPACITANCE (Note 3)	CAPACITANCE (Note 4)
nA	$\mu\text{A}$	$\mu\text{A}$	$\mu\text{A}$	pF	pF
25	0.5	50	100	4.0	2.8

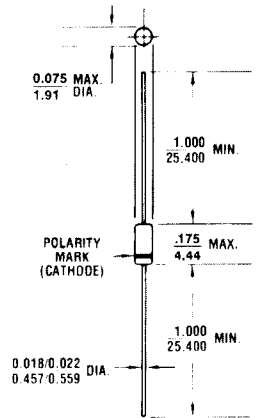
NOTE 1:  $I_F = I_R = 10\text{ mA}$ ,  $R_L = 100\text{ ohms}$ .

NOTE 2:  $I_F = 50\text{ mA dc}$ .

NOTE 3:  $V_R = 0\text{ V}$ ,  $f = 1\text{ MHz}$ ,  $V_{SIG} = 50\text{ mV (pk to pk)}$ .

NOTE 4:  $V_R = 1.5\text{ V dc}$ ,  $f = 1\text{ MHz}$ ,  $V_{SIG} = 50\text{ mV (pk to pk)}$ .

**MILITARY SWITCHING DIODES**



**FIGURE 1**

All dimensions in INCH  
m.m.

**MECHANICAL CHARACTERISTICS**

CASE: Hermetically sealed glass case (DO-35).

LEAD MATERIAL: Tinned copper clad steel.

MARKING: Body painted, alpha numeric.

POLARITY: Cathode band.